Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.185 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.370 inches	
Joint Electronic Device Engineering Council/jedec/case Outline I	Designation:
То-78	
Electrode Internally-electrically Connected To Case:	
Collector	
Component Name And Quantity:	
2 semiconductor device diode	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all semiconductor device diode	
Voltage Rating In Volts Per Characteristic:	
30.0 breakdown voltage, dc all semiconductor device diode	
Current Rating Per Characteristic:	
10.00 milliamperes reverse current, dc all semiconductor device diod	de
Power Rating Per Characteristic:	
300.0 milliwatts total power dissipation all semiconductor device diod	е
Capacitance Rating In Picofarads:	
1.0 all semiconductor device diode	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius ambient air	
Special Features:	
All semiconductor device diode junction pattern arrangement: pn	
Terminal Type And Quantity:	
4 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
- A110a0	